

www.ti.com

SNOSA43A - MAY 2004 - REVISED APRIL 2013

LMH6682/6683 190MHz Single Supply, Dual and Triple Operational Amplifiers

Check for Samples: LMH6682, LMH6683

### **FEATURES**

 $V_{S} = \pm 5V$ ,  $T_{A} = 25^{\circ}C$ ,  $R_{L} = 100\Omega$ , A = +2 (Typical Values Unless Specified)

- DG error 0.01%
- DP error 0.08°
- -3dB BW (A = +2) 190MHz
- Slew rate ( $V_s = \pm 5V$ ) 940V/µs
- Supply Current 6.5mA/amp
- Output Current +80/-90mA
- Input Common Mode Voltage 0.5V Beyond V<sup>-</sup>,1.7V from V<sup>+</sup>
- Output Voltage Swing ( $R_L = 2k\Omega$ ) 0.8V from Rails
- Input Voltage Noise (100KHz) 12nV/VHz

### APPLICATIONS

- CD/DVD ROM
- ADC Buffer Amp
- **Portable Video**
- **Current Sense Buffer**
- **Portable Communications**

#### DESCRIPTION

The LMH6682 and LMH6683 are high speed operational amplifiers designed for use in modern video systems. These single supply monolithic amplifiers extend TI's feature-rich, high value video portfolio to include a dual and a triple version. The important video specifications of differential gain (± 0.01% typ.) and differential phase (±0.08 degrees) combined with an output drive current in each amplifier of 85mA make the LMH6682 and LMH6683 excellent choices for a full range of video applications.

Voltage feedback topology in operational amplifiers assures maximum flexibility and ease of use in high speed amplifier designs. The LMH6682/83 is fabricated in TI's VIP10 process. This advanced process provides a superior ratio of speed to quiescient current consumption and assures the user of high-value amplifier designs. Advanced technology and circuit design enables in these amplifiers a -3db bandwidth of 190MHz, a slew rate of 940V/µsec, and stability for gains of less than -1 and greater than +2.

The input stage design of the LM6682/83 enables an input signal range that extends below the negative rail. The output stage voltage range reaches to within 0.8V of either rail when driving a 2kΩ load. Other attractive features include fast settling and low distortion. Other applications for these amplifiers include servo control designs. These applications are sensitive to amplifiers that exhibit phase reversal when the inputs exceed the rated voltage range. The LMH6682/83 amplifiers are designed to be immune to phase reversal when the specified input range is exceeded. See applications section. This feature makes for design simplicity and flexibility in many industrial applications.

The LMH6682 dual operational amplifier is offered in miniature surface mount packages, SOIC-8, and VSSOP-8. The LMH6683 triple amplifier is offered in SOIC-14 and TSSOP-14.



Please be aware that an important notice concerning availability, standard warranty, and use in critical applications of Texas Instruments semiconductor products and disclaimers thereto appears at the end of this data sheet. All trademarks are the property of their respective owners.







#### Figure 2. SOIC-14/TSSOP-14 (LMH6683) Top View

These devices have limited built-in ESD protection. The leads should be shorted together or the device placed in conductive foam during storage or handling to prevent electrostatic damage to the MOS gates.

#### Absolute Maximum Ratings<sup>(1)(2)</sup>

| ESD Tolerance                                     | Human Body Model                 | 2KV <sup>(3)</sup>                         |
|---|----------------------------------|--|
|   | Machine Model                    | 200V <sup>(4)</sup>                        |
| V <sub>IN</sub> Differential                      |                                  | ±2.5V                                      |
| Output Short Circuit Duration                     |                                  | See <sup>(5)(6)</sup>                      |
| Input Current                                     |                                  | ±10mA                                      |
| Supply Voltage (V <sup>+</sup> - V <sup>-</sup> ) |                                  | 12.6V                                      |
| Voltage at Input/Output pins                      |                                  | V <sup>+</sup> +0.8V, V <sup>−</sup> −0.8V |
| Soldering Information                             | Infrared or Convection (20 sec.) | 235°C                                      |
|   | Wave Soldering (10 sec.)         | 260°C                                      |
| Storage Temperature Range                         |                                  | -65°C to +150°C                            |
| Junction Temperature <sup>(7)</sup>               |                                  | +150°C                                     |

(1) Absolute maximum Ratings indicate limits beyond which damage to the device may occur. Operating Ratings indicate conditions for which the device is intended to be functional, but specific performance is not ensured. For ensured specifications and the test conditions, see the Electrical Characteristics.

- (2) If Military/Aerospace specified devices are required, please contact the TI Sales Office/ Distributors for availability and specifications.
- (3) Human body model,  $1.5k\Omega$  in series with 100pF.
- (4) Machine Model, 0Ω in series with 200pF.

(5) Applies to both single-supply and split-supply operation. Continuous short circuit operation at elevated ambient temperature can result in exceeding the maximum allowed junction temperature of 150°C.

(6) Output short circuit duration is infinite for  $V_S < 6V$  at room temperature and below. For  $V_S > 6V$ , allowable short circuit duration is 1.5ms. (7) The maximum power dissipation is a function of  $T_{J(MAX)}$ ,  $\theta_{JA}$ , and  $T_A$ . The maximum allowable power dissipation at any ambient

temperature is  $P_D = (T_{J(MAX)} - T_A)/\theta_{JA}$ . All numbers apply for packages soldered directly onto a PC board.

#### **Operating Ratings**<sup>(1)</sup>

| Supply Voltage $(V^+ - V^-)$               | 3V to 12V |                |
|--|-----------|----------------|
| Operating Temperature Range <sup>(2)</sup> |           | −40°C to +85°C |
| Package Thermal Resistance <sup>(2)</sup>  | SOIC-8    | 190°C/W        |
|  | VSSOP-8   | 235°C/W        |
|  | SOIC-14   | 145°C/W        |
|  | TSSOP-14  | 155°C/W        |

(1) Absolute maximum Ratings indicate limits beyond which damage to the device may occur. Operating Ratings indicate conditions for which the device is intended to be functional, but specific performance is not ensured. For ensured specifications and the test conditions, see the Electrical Characteristics.

(2) The maximum power dissipation is a function of  $T_{J(MAX)}$ ,  $\theta_{JA}$ , and  $T_A$ . The maximum allowable power dissipation at any ambient temperature is  $P_D = (T_{J(MAX)} - T_A)/|\theta_{JA}|$ . All numbers apply for packages soldered directly onto a PC board.

www.ti.com

www.ti.com

#### **5V Electrical Characteristics**

Unless otherwise specified, all limits ensured for at  $T_J = 25^{\circ}C$ ,  $V^+ = 5V$ ,  $V^- = 0V$ ,  $V_O = V_{CM} = V^+/2$ , and  $R_L = 100\Omega$  to  $V^+/2$ ,  $R_F = 510\Omega$ . **Boldface** limits apply at the temperature extremes.

| Symbol                         | Parameter                           | Conditions  | Min <sup>(1)</sup>  | Typ <sup>(2)</sup> | Max <sup>(1)</sup> | Units   |
|--------------------------------|-------------------------------------|---|---------------------|--------------------|--------------------|---------|
| SSBW                           | -3dB BW                             | $A = +2, V_{OUT} = 200 mV_{PP}$   | 140                 | 180                |                    | N.41.1_ |
|                                |                                     | $A = -1, V_{OUT} = 200 mV_{PP}$   |                     | 180                |                    | MHZ     |
| GFP                            | Gain Flatness Peaking               | A = +2, $V_{OUT}$ = 200m $V_{PP}$<br>DC to 100MHz   |                     | 2.1                |                    | dB      |
| GFR                            | Gain Flatness Rolloff               | A = +2, $V_{OUT}$ = 200m $V_{PP}$<br>DC to 100MHz   |                     | 0.1                |                    | dB      |
| LPD 1°                         | 1° Linear Phase Deviation           | $A = +2, V_{OUT} = 200 \text{mV}_{PP}, \pm 1^{\circ}$   |                     | 40                 |                    | MHz     |
| GF <sub>0.1dB</sub>            | 0.1dB Gain Flatness                 | A = +2, $\pm 0.1$ dB, V <sub>OUT</sub> = 200mV <sub>PP</sub>  |                     | 25                 |                    | MHz     |
| FPBW                           | Full Power -1dB Bandwidth           | $A = +2$ , $V_{OUT} = 2V_{PP}$  |                     | 110                |                    | MHz     |
| DG                             | Differential Gain<br>NTSC 3.58MHz   | A = +2, R <sub>L</sub> = 150 $\Omega$ to V <sup>+</sup> /2<br>Pos video only V <sub>CM</sub> = 2V                       |                     | 0.03               |                    | %       |
| DP                             | Differential Phase<br>NTSC 3.58MHz  | A = +2, R <sub>L</sub> = 150 $\Omega$ to V <sup>+</sup> /2<br>Pos video only V <sub>CM</sub> = 2V                       |                     | 0.05               |                    | deg     |
| Time Dom                       | ain Response                        |   |                     |                    |                    |         |
| T <sub>r</sub> /T <sub>f</sub> | Rise and Fall Time                  | 20-80%, $V_O = 1V_{PP}$ , $A_V = +2$  |                     | 2.1                |                    | 20      |
|                                |                                     | 20-80%, $V_0 = 1V_{PP}$ , $A_V = -1$  |                     | 2                  |                    | 115     |
| OS                             | Overshoot                           | $A = +2, V_{O} = 100 mV_{PP}$   |                     | 22                 |                    | %       |
| Ts                             | Settling Time                       | $V_O = 2V_{PP}, \pm 0.1\%, A_V = +2$  |                     | 49                 |                    | ns      |
| SR                             | Slew Rate <sup>(3)</sup>            | $A = +2$ , $V_{OUT} = 3V_{PP}$  |                     | 520                |                    | \//ue   |
|                                |                                     | $A = -1$ , $V_{OUT} = 3V_{PP}$  |                     | 500                |                    | v/µs    |
| Distortion                     | and Noise Response                  |   |                     |                    |                    |         |
| HD2                            | 2 <sup>nd</sup> Harmonic Distortion | f = 5MHz, $V_O$ = 2 $V_{PP}$ , A = +2, $R_L$ = 2k $\Omega$  |                     | -60                |                    |         |
|                                |                                     | f = 5MHz, $V_0$ = 2 $V_{PP}$ , A = +2, R <sub>L</sub> = 100 $\Omega$  |                     | -61                |                    | dBc     |
| HD3                            | 3 <sup>rd</sup> Harmonic Distortion | f = 5MHz, $V_O$ = 2 $V_{PP}$ , A = +2, $R_L$ = 2 $k\Omega$  |                     | -77                |                    |         |
|                                |                                     | f = 5MHz, $V_O$ = 2 $V_{PP}$ , A = +2, R <sub>L</sub> = 100 $\Omega$  |                     | -54                |                    | dBc     |
| THD                            | Total Harmonic Distortion           | f = 5MHz, $V_O$ = 2 $V_{PP}$ , A = +2, $R_L$ = 2 $k\Omega$  |                     | -60                |                    |         |
|                                |                                     | f = 5MHz, $V_0$ = 2 $V_{PP}$ , A = +2, R <sub>L</sub> = 100 $\Omega$  |                     | -53                |                    | dBc     |
| en                             | Input Referred Voltage Noise        | f = 1kHz  |                     | 17                 |                    | nV/√Hz  |
|                                |                                     | f = 100kHz  |                     | 12                 |                    |         |
| i <sub>n</sub>                 | Input Referred Current Noise        | f = 1kHz  |                     | 8                  |                    | pA/√Hz  |
|                                |                                     | f = 100kHz  |                     | 3                  |                    |         |
| СТ                             | Cross-Talk Rejection (Amplifier)    | f = 5MHz, A = +2, SND: R <sub>L</sub> = 100Ω<br>RCV: R <sub>F</sub> = R <sub>G</sub> = 510Ω                             |                     | -77                |                    | dB      |
| Static, DC                     | Performance                         |   |                     |                    |                    |         |
| A <sub>VOL</sub>               | Large Signal Voltage Gain           | $\label{eq:VO} \begin{array}{l} V_O = 1.25 V \text{ to } 3.75 V, \\ R_L = 2 k \Omega \text{ to } V^{+}\!/2 \end{array}$ | 85                  | 95                 |                    |         |
|                                |                                     | $V_{O} = 1.5V$ to 3.5V,<br>R <sub>L</sub> = 150 $\Omega$ to V <sup>+</sup> /2   | 75                  | 85                 |                    | dB      |
|                                |                                     | $V_{O} = 2V \text{ to } 3V,$<br>$R_{L} = 50\Omega \text{ to } V^{+}/2$  | 70                  | 80                 |                    |         |
| CMVR                           | Input Common-Mode Voltage<br>Range  | CMRR ≥ 50dB   | -0.2<br><b>-0.1</b> | -0.5               |                    |         |
|                                |                                     |   | 3.0<br><b>2.8</b>   | 3.3                |                    | v       |

(1) All limits are ensured by testing or statistical analysis.

(2) Typical values represent the most likely parametric norm.

(3) Slew rate is the average of the rising and falling slew rates

Copyright © 2004–2013, Texas Instruments Incorporated



www.ti.com

### SNOSA43A – MAY 2004 – REVISED APRIL 2013

#### **5V Electrical Characteristics (continued)**

Unless otherwise specified, all limits ensured for at  $T_J = 25^{\circ}C$ ,  $V^+ = 5V$ ,  $V^- = 0V$ ,  $V_O = V_{CM} = V^+/2$ , and  $R_L = 100\Omega$  to  $V^+/2$ ,  $R_F = 510\Omega$ . **Boldface** limits apply at the temperature extremes.

| Symbol             | Parameter  | Conditions                                 | Min <sup>(1)</sup>  | Typ <sup>(2)</sup> | Max <sup>(1)</sup>  | Units |  |
|--------------------|--|--|---------------------|--------------------|---------------------|-------|--|
| V <sub>OS</sub>    | Input Offset Voltage                                 |  |                     | ±1.1               | ±5<br><b>±7</b>     | mV    |  |
| TC V <sub>OS</sub> | Input Offset Voltage Average<br>Drift                | See <sup>(4)</sup>                         |                     | ±2                 |                     | µV/°C |  |
| Ι <sub>Β</sub>     | Input Bias Current                                   | See <sup>(5)</sup>                         |                     | -5                 | -20<br><b>-30</b>   | μΑ    |  |
| TC <sub>IB</sub>   | Input Bias Current Drift                             |  |                     | 0.01               |                     | nA/°C |  |
| I <sub>OS</sub>    | Input Offset Current                                 |  |                     | 50                 | 300<br><b>500</b>   | nA    |  |
| CMRR               | Common Mode Rejection Ratio                          | V <sub>CM</sub> Stepped from 0V to 3.0V    | 72                  | 82                 |                     | dB    |  |
| +PSRR              | Positive Power Supply Rejection Ratio                | $V^+$ = 4.5V to 5.5V, $V_{CM}$ = 1V        | 70                  | 76                 |                     | dB    |  |
| I <sub>S</sub>     | Supply Current (per channel)                         | No load                                    |                     | 6.5                | 9<br>11             | mA    |  |
| Miscellane         | ous Performance                                      |  | i                   |                    |                     |       |  |
| Vo                 | Output Swing<br>High                                 | $R_L = 2k\Omega$ to V <sup>+</sup> /2      | 4.10<br><b>3.8</b>  | 4.25               |                     |       |  |
|                    |  | $R_L = 150\Omega$ to V <sup>+</sup> /2     | 3.90<br><b>3.70</b> | 4.19               |                     | V     |  |
|                    |  | $R_L = 75\Omega$ to V <sup>+</sup> /2      | 3.75<br><b>3.50</b> | 4.15               |                     |       |  |
|                    | Output Swing<br>Low                                  | $R_L = 2k\Omega$ to V <sup>+</sup> /2      |                     | 800                | 920<br><b>1100</b>  |       |  |
|                    |  | $R_L = 150\Omega$ to V <sup>+</sup> /2     |                     | 870                | 970<br><b>1200</b>  | mV    |  |
|                    |  | R $_{L} = 75\Omega$ to V <sup>+</sup> /2   |                     | 885                | 1100<br><b>1250</b> |       |  |
| I <sub>OUT</sub>   | Output Current                                       | $V_{O} = 1V$ from either supply rail       | ±40                 | +80/-75            |                     | mA    |  |
| I <sub>SC</sub>    | Output Short Circuit<br>Current <sup>(6)(7)(8)</sup> | Sourcing to V <sup>+</sup> /2              | -100<br><b>-80</b>  | -155               |                     | 0     |  |
|                    |  | Sinking from V <sup>+</sup> /2             | 100<br><b>80</b>    | 220                |                     | mA    |  |
| R <sub>IN</sub>    | Common Mode Input Resistance                         |  |                     | 3                  |                     | MΩ    |  |
| C <sub>IN</sub>    | Common Mode Input<br>Capacitance                     |  |                     | 1.6                |                     | pF    |  |
| R <sub>OUT</sub>   | Output Resistance Closed Loop                        | $f = 1 \text{ Hz}, A = +2, R_L = 50\Omega$ |                     | 0.02               |                     | 0     |  |
|                    |  | $f = 1MHz, A = +2, R_1 = 50\Omega$         |                     | 0.12               |                     | 12    |  |

(4) Offset Voltage average drift determined by dividing the change in V<sub>OS</sub> at temperature extremes into the total temperature change.

(5) Positive current corresponds to current flowing into the device.

(6) Short circuit test is a momentary test. See next note.

(7) Output short circuit duration is infinite for  $V_S < 6V$  at room temperature and below. For  $V_S > 6V$ , allowable short circuit duration is 1.5ms.

(8) Positive current corresponds to current flowing into the device.

#### www.ti.com

#### ±5V Electrical Characteristics

Unless otherwise specified, all limits ensured for at  $T_J = 25^{\circ}C$ ,  $V^+ = 5V$ ,  $V^- = -5V$ ,  $V_O = V_{CM} = 0V$ , and  $R_L = 100\Omega$  to 0V,  $R_F = 510\Omega$ . **Boldface** limits apply at the temperature extremes.

| Symbol                         | Parameter                           | Conditions   | Min <sup>(1)</sup>  | Тур <sup>(2)</sup> | Max <sup>(1)</sup> | Units  |
|--------------------------------|-------------------------------------|--|---------------------|--------------------|--------------------|--------|
| SSBW                           | -3dB BW                             | $A = +2, V_{OUT} = 200 mV_{PP}$  | 150                 | 190                |                    |        |
|                                |                                     | $A = -1$ , $V_{OUT} = 200 m V_{PP}$  |                     | 190                |                    | IVIEZ  |
| GFP                            | Gain Flatness Peaking               | A = +2, $V_{OUT}$ = 200m $V_{PP}$<br>DC to 100MHz  |                     | 1.7                |                    | dB     |
| GFR                            | Gain Flatness Rolloff               | A = +2, $V_{OUT}$ = 200m $V_{PP}$<br>DC to 100MHz  |                     | 0.1                |                    | dB     |
| LPD 1°                         | 1° Linear Phase Deviation           | $A = +2, V_{OUT} = 200 mV_{PP}, \pm 1^{\circ}$   |                     | 40                 |                    | MHz    |
| GF <sub>0.1dB</sub>            | 0.1dB Gain Flatness                 | A = +2, $\pm 0.1$ dB, V <sub>OUT</sub> = 200mV <sub>PP</sub>   |                     | 25                 |                    | MHz    |
| FPBW                           | Full Power -1dB Bandwidth           | $A = +2$ , $V_{OUT} = 2V_{PP}$   |                     | 120                |                    | MHz    |
| DG                             | Differential Gain<br>NTSC 3.58MHz   | A = +2, $R_L$ = 150 $\Omega$ to 0V   |                     | 0.01               |                    | %      |
| DP                             | Differential Phase<br>NTSC 3.58MHz  | A = +2, R <sub>L</sub> = 150 $\Omega$ to 0V  |                     | 0.08               |                    | deg    |
| Time Doma                      | in Response                         |  |                     |                    |                    |        |
| T <sub>r</sub> /T <sub>f</sub> | Rise and Fall Time                  | 20-80%, V <sub>O</sub> = 1V <sub>PP</sub> , A = +2   |                     | 1.9                |                    | nc     |
|                                |                                     | 20-80%, V <sub>O</sub> = 1V <sub>PP</sub> , A = −1   |                     | 2                  |                    | 115    |
| OS                             | Overshoot                           | $A = +2, V_0 = 100 mV_{PP}$  |                     | 19                 |                    | %      |
| Ts                             | Settling Time                       | $V_{O} = 2V_{PP}, \pm 0.1\%, A = +2$   |                     | 42                 |                    | ns     |
| SR                             | Slew Rate <sup>(3)</sup>            | $A = +2, V_{OUT} = 6V_{PP}$  |                     | 940                |                    | V/ue   |
|                                |                                     | $A = -1$ , $V_{OUT} = 6V_{PP}$   |                     | 900                |                    | v/µs   |
| Distortion a                   | nd Noise Response                   |  |                     |                    |                    |        |
| HD2                            | 2 <sup>nd</sup> Harmonic Distortion | f = 5MHz, $V_O = 2V_{PP}$ , A = +2, $R_L = 2k\Omega$   |                     | -63                |                    |        |
|                                |                                     | f = 5MHz, $V_O$ = 2 $V_{PP}$ , A = +2, R <sub>L</sub> = 100 $\Omega$   |                     | -66                |                    | dBc    |
| HD3                            | 3 <sup>rd</sup> Harmonic Distortion | f = 5MHz, $V_O$ = 2 $V_{PP}$ , A = +2, R <sub>L</sub> = 2k $\Omega$  |                     | -82                |                    |        |
|                                |                                     | f = 5MHz, $V_O$ = 2 $V_{PP}$ , A = +2, R <sub>L</sub> = 100 $\Omega$   |                     | -54                |                    | dBc    |
| THD                            | Total Harmonic Distortion           | f = 5MHz, $V_O$ = 2 $V_{PP}$ , A = +2, $R_L$ = 2 $k\Omega$   |                     | -63                |                    |        |
|                                |                                     | f = 5MHz, $V_0$ = 2 $V_{PP}$ , A = +2, R <sub>L</sub> = 100 $\Omega$   |                     | -54                |                    | dBc    |
| e <sub>n</sub>                 | Input Referred Voltage Noise        | f = 1kHz   |                     | 18                 |                    | nV/√Hz |
|                                |                                     | f = 100kHz   |                     | 12                 |                    |        |
| i <sub>n</sub>                 | Input Referred Current Noise        | f = 1kHz   |                     | 6                  |                    | pA/√Hz |
|                                |                                     | f = 100kHz   |                     | 3                  |                    |        |
| СТ                             | Cross-Talk Rejection (Amplifier)    | f = 5MHz, A = +2, SND: R <sub>L</sub> = 100Ω<br>RCV: R <sub>F</sub> = R <sub>G</sub> = 510Ω                              |                     | -78                |                    | dB     |
| Static, DC F                   | Performance                         |  | 1                   |                    |                    |        |
| A <sub>VOL</sub>               | Large Signal Voltage Gain           | $\label{eq:VO} \begin{array}{l} V_O = -3.75 V \mbox{ to } 3.75 V, \\ R_L = 2 k \Omega \mbox{ to } V^{+} / 2 \end{array}$ | 87                  | 100                |                    |        |
|                                |                                     | $V_{O} = -3.5V$ to 3.5V,<br>R <sub>L</sub> = 150 $\Omega$ to V <sup>+</sup> /2   | 80                  | 90                 |                    | dB     |
|                                |                                     | $V_{O} = -3V$ to 3V,<br>R <sub>L</sub> = 50 $\Omega$ to V <sup>+</sup> /2  | 75                  | 85                 |                    |        |
| CMVR                           | Input Common Mode Voltage<br>Range  | CMRR ≥ 50dB  | -5.2<br><b>-5.1</b> | -5.5               |                    | V      |
|                                |                                     |  | 3.0<br><b>2.8</b>   | 3.3                |                    | v      |

(1) All limits are ensured by testing or statistical analysis.

(2) Typical values represent the most likely parametric norm.

(3) Slew rate is the average of the rising and falling slew rates

Copyright © 2004–2013, Texas Instruments Incorporated



www.ti.com

## SNOSA43A-MAY 2004-REVISED APRIL 2013

#### ±5V Electrical Characteristics (continued)

Unless otherwise specified, all limits ensured for at  $T_J = 25^{\circ}C$ ,  $V^+ = 5V$ ,  $V^- = -5V$ ,  $V_O = V_{CM} = 0V$ , and  $R_L = 100\Omega$  to 0V,  $R_F = -5V$ ,  $V_O = V_{CM} = 0V$ ,  $V_C = 100\Omega$  to 0V,  $R_F = -5V$ ,  $V_C = 100\Omega$  to 0V,  $R_F = -5V$ ,  $V_C = 100\Omega$  to 0V,  $R_F = -5V$ ,  $V_C = 100\Omega$  to 0V,  $R_F = -5V$ ,  $V_C = 100\Omega$  to 0V,  $R_F = -5V$ ,  $V_C = 100\Omega$  to 0V,  $R_F = -5V$ ,  $V_C = 100\Omega$  to 0V,  $R_F = -5V$ ,  $V_C = 100\Omega$  to 0V,  $R_F = -5V$ ,  $V_C = 100\Omega$  to 0V,  $R_F = -5V$ ,  $V_C = 100\Omega$  to 0V,  $R_F = -5V$ ,  $V_C = 100\Omega$ ,  $R_C = 100\Omega$ , 510 $\Omega$ . **Boldface** limits apply at the temperature extremes.

| Symbol             | Parameter  | Conditions   | Min <sup>(1)</sup>  | Typ <sup>(2)</sup> | Max <sup>(1)</sup>    | Units |
|--------------------|--|--|---------------------|--------------------|-----------------------|-------|
| V <sub>OS</sub>    | Input Offset Voltage                                 |  |                     | ±1                 | ±5<br><b>±7</b>       | mV    |
| TC V <sub>OS</sub> | Input Offset Voltage Average<br>Drift                | See <sup>(4)</sup>                                     |                     | ±2                 |                       | µV/°C |
| Ι <sub>Β</sub>     | Input Bias Current                                   | See <sup>(5)</sup>                                     |                     | -5                 | -20<br>- <b>30</b>    | μΑ    |
| TC <sub>IB</sub>   | Input Bias Current Drift                             |  |                     | 0.01               |                       | nA/°C |
| I <sub>OS</sub>    | Input Offset Current                                 |  |                     | 50                 | 300<br><b>500</b>     | nA    |
| CMRR               | Common Mode Rejection Ratio                          | V <sub>CM</sub> Stepped from -5V to 3.0V               | 75                  | 84                 |                       | dB    |
| +PSRR              | Positive Power Supply Rejection Ratio                | V <sup>+</sup> = 8.5V to 9.5V,<br>V <sup>−</sup> = −1V | 75                  | 82                 |                       | dB    |
| -PSRR              | Negative Power Supply Rejection Ratio                | $V^{-} = -4.5V$ to $-5.5V$ ,<br>$V^{+} = 5V$           | 78                  | 85                 |                       | dB    |
| I <sub>S</sub>     | Supply Current (per channel)                         | No load  |                     | 6.5                | 9.5<br><b>11</b>      | mA    |
| Miscellaneo        | bus Performance                                      | •  |                     |                    |                       |       |
| Vo                 | Output Swing<br>High                                 | $R_L = 2k\Omega$ to 0V                                 | 4.10<br><b>3.80</b> | 4.25               |                       |       |
|                    |  | $R_L = 150\Omega$ to 0V                                | 3.90<br><b>3.70</b> | 4.20               |                       | V     |
|                    |  | $R_L = 75\Omega$ to 0V                                 | 3.75<br><b>3.50</b> | 4.18               |                       |       |
|                    | Output Swing<br>Low                                  | $R_L = 2k\Omega$ to 0V                                 |                     | -4.19              | -4.07<br><b>-3.80</b> |       |
|                    |  | $R_L = 150\Omega$ to 0V                                |                     | -4.05              | -3.89<br><b>-3.65</b> | mV    |
|                    |  | R $_{\rm L}$ = 75 $\Omega$ to 0V                       |                     | -4.00              | -3.70<br><b>-3.50</b> |       |
| I <sub>OUT</sub>   | Output Current                                       | $V_{O} = 1V$ from either supply rail                   | ±45                 | +85/-80            |                       | mA    |
| I <sub>SC</sub>    | Output Short Circuit<br>Current <sup>(6)(7)(8)</sup> | Sourcing to 0V   | -120<br><b>-100</b> | -180               |                       | ~ ^   |
|                    |  | Sinking from 0V  | 120<br><b>100</b>   | 230                |                       | ma    |
| R <sub>IN</sub>    | Common Mode Input Resistance                         |  |                     | 4                  |                       | MΩ    |
| C <sub>IN</sub>    | Common Mode Input<br>Capacitance                     |  |                     | 1.6                |                       | pF    |
| R <sub>OUT</sub>   | Output Resistance Closed Loop                        | $f = 1kHz$ , $A = +2$ , $R_L = 50\Omega$               |                     | 0.02               |                       |       |
|                    |  | $f = 1MHz, A = +2, R_L = 50\Omega$                     |                     | 0.12               |                       | 12    |

(4) Offset Voltage average drift determined by dividing the change in V<sub>OS</sub> at temperature extremes into the total temperature change.
(5) Positive current corresponds to current flowing into the device.

(6) Short circuit test is a momentary test. See next note.

Output short circuit duration is infinite for  $V_S < 6V$  at room temperature and below. For  $V_S > 6V$ , allowable short circuit duration is 1.5ms. (7)

(8) Positive current corresponds to current flowing into the device.

7



**Typical Schematic** 

11 10nF

v<sub>cc</sub> Q







Non-Inverting Frequency Response for Various Gain



Non-Inverting Phase vs. Frequency for Various Gain





**Inverting Frequency Response for Various Gain** 



Inverting Phase vs. Frequency for Various Gain



Submit Documentation Feedback

Copyright © 2004–2013, Texas Instruments Incorporated

**Typical Performance Characteristics** 



www.ti.com



### LMH6682, LMH6683

SNOSA43A - MAY 2004 - REVISED APRIL 2013

#### www.ti.com

#### **Typical Performance Characteristics (continued)**

At  $T_A = 25^{\circ}C$ ,  $V^+ = +5V$ ,  $V^- = -5V$ ,  $R_F = 510\Omega$  for A = +2; unless otherwise specified.













Inverting Frequency Response Over Temperature







Copyright © 2004–2013, Texas Instruments Incorporated

www.ti.com









www.ti.com





V<sub>OS</sub> (mV)

Isource (mA)

OUTPUT POWER (dB)

14



Texas

www.ti.com



### LMH6682, LMH6683

SNOSA43A - MAY 2004 - REVISED APRIL 2013



### APPLICATIONS SECTION

#### LARGE SIGNAL BEHAVIOR

Amplifying high frequency signals with large amplitudes (as in video applications) has some special aspects to look after. The bandwidth of the Op Amp for large amplitudes is less than the small signal bandwidth because of slew rate limitations. While amplifying pulse shaped signals the slew rate properties of the OpAmp become more important at higher amplitude ranges. Due to the internal structure of an Op Amp the output can only change with a limited voltage difference per time unit (dV/dt). This can be explained as follows: To keep it simple, assume that an Op Amp consists of two parts; the input stage and the output stage. In order to stabilize the Op Amp, the output stage has a compensation capacitor in its feedback path. This Miller C integrates the current from the input stage and determines the pulse response of the Op Amp. The input stage must charge/discharge the feedback capacitor, as can be seen in Figure 51.



Figure 51.

When a voltage transient is applied to the non inverting input of the Op Amp, the current from the input stage will charge the capacitor and the output voltage will slope up. The overall feedback will subtract the gradually increasing output voltage from the input voltage. The decreasing differential input voltage is converted into a current by the input stage (Gm).

| $I^{*}\Delta t = C^{*}\Delta V$ | (1) |
|---------------------------------|-----|
| $\Delta V / \Delta t = I / C$   | (2) |
| I=ΔV*Gm                         | (3) |

where I = current

t = time

16

C = capacitance

V = voltage

Gm = transconductance

 $\Delta V/\Delta t = Imax/C$ 

```
Slew rate \Delta V / \Delta t = volt/second
```

In most amplifier designs the current I is limited for high differential voltages (Gm becomes zero). The slew rate will than be limited as well:

(4)

The LMH6682/83 has a different setup of the input stage. It has the property to deliver more current to the output stage when the input voltage is higher (class AB input). The current into the Miller capacitor exhibits an exponential character, while this current in other Op Amp designs reaches a saturation level at high input levels: (see Figure 52)



www.ti.com



Figure 52.

This property of the LMH6682/83 guaranties a higher slew rate at higher differential input voltages.  $\Delta V/\Delta t = \Delta V^*Gm/C$ 

In Figure 53 one can see that a higher transient voltage than will lead to a higher slew rate.





#### HANDLING VIDEO SIGNALS

When handling video signals, two aspects are very important especially when cascading amplifiers in a NTSC- or PAL video system. A composite video signal consists of both amplitude and phase information. The amplitude represents saturation while phase determines color (color burst is 3.59MHz for NTSC and 4.58MHz for PAL systems). In this case it is not only important to have an accurate amplification of the amplitude but also it is important not to add a varying phase shift to the video signals. It is a known phenomena that at different dc levels over a certain load the phase of the amplified signal will vary a little bit. In a video chain many amplifiers will be cascaded and all errors will be added together. For this reason, it is necessary to have strict requirements for the variation in gain and phase in conjunction to different dc levels. As can be seen in the tables the number for the differential gain for the LMH6682/83 is only 0.01% and for the differential phase it is only 0.08° at a supply voltage of ±5V. Note that the phase is very dependent of the load resistance, mainly because of the dc current delivered by the parts output stage into the load. For more information about differential gain and phase and how to measure it see Application Note OA-24 SNOA370 which can be found on via TI's home page http://www.ti.com

www.ti.com

FXAS

NSTRUMENTS

(5)



www.ti.com

#### OUTPUT PHASE REVERSAL

This is a problem with some operational amplifiers. This effect is caused by phase reversal in the input stage due to saturation of one or more of the transistors when the inputs exceed the normal expected range of voltages. Some applications, such as servo control loops among others, are sensitive to this kind of behavior and would need special safeguards to ensure proper functioning. The LMH6682/6683 is immune to output phase reversal with input overload. With inputs exceeded, the LMH6682/6683 output will stay at the clamped voltage from the supply rail. Exceeding the input supply voltages beyond the Absolute Maximum Ratings of the device could however damage or otherwise adversely effect the reliability or life of the device.

#### DRIVING CAPACITIVE LOADS

The LMH6682/6683 can drive moderate values of capacitance by utilizing a series isolation resistor between the output and the capacitive load. Capacitive load tolerance will improve with higher closed loop gain values. Applications such as ADC buffers, among others, present complex and varying capacitive loads to the Op Amp; best value for this isolation resistance is often found by experimentation and actual trial and error for each application.

#### DISTORTION

Applications with demanding distortion performance requirements are best served with the device operating in the inverting mode. The reason for this is that in the inverting configuration, the input common mode voltage does not vary with the signal and there is no subsequent ill effects due to this shift in operating point and the possibility of additional non-linearity. Moreover, under low closed loop gain settings (most suited to low distortion), the non-inverting configuration is at a further disadvantage of having to contend with the input common voltage range. There is also a strong relationship between output loading and distortion performance (i.e.  $2k\Omega vs. 100\Omega$  distortion improves by about 15dB @1MHz) especially at the lower frequency end where the distortion tends to be lower. At higher frequency, this dependence diminishes greatly such that this difference is only about 5dB at 10MHz. But, in general, lighter output load leads to reduced HD3 term and thus improves THD. (See Harmonic Distortion plots, Figures 19 through 23).

#### PRINTED CIRCUIT BOARD LAYOUT AND COMPONENT VALUES SELECTION

Generally it is a good idea to keep in mind that for a good high frequency design both the active parts and the passive ones are suitable for the purpose you are using them for. Amplifying frequencies of several hundreds of MHz is possible while using standard resistors but it makes life much easier when using surface mount ones. These resistors (and capacitors) are smaller and therefore parasitics have lower values and will have less influence on the properties of the amplifier. Another important issue is the PCB, which is no longer a simple carrier for all the parts and a medium to interconnect them. The board becomes a real part itself, adding its own high frequency properties to the overall performance of the circuit. It's good practice to have at least one ground plane on a PCB giving a low impedance path for all decouplings and other ground connections. Care should be taken especially that on board transmission lines have the same impedance as the cables they are connected to (i.e. 50 $\Omega$  for most applications and 75 $\Omega$  in case of video and cable TV applications). These transmission lines usually require much wider traces on a standard double sided PCB than needed for a 'normal' connection. Another important issue is that inputs and outputs must not 'see' each other or are routed together over the PCB at a small distance. Furthermore it is important that components are placed as flat as possible on the surface of the PCB. For higher frequencies a long lead can act as a coil, a capacitor or an antenna. A pair of leads can even form a transformer. Careful design of the PCB avoids oscillations or other unwanted behavior. When working with really high frequencies, the only components which can be used will be the surface mount ones (for more information see OA-15 SNOA367).

As an example of how important the component values are for the behavior of your circuit, look at the following case: On a board with good high frequency layout, an amplifier is placed. For the two (equal) resistors in the feedback path, 5 different values are used to set the gain to +2. The resistors vary from  $200\Omega$  to  $3k\Omega$ .







Figure 54.

In Figure 54 it can be seen that there's more peaking with higher resistor values, which can lead to oscillations and bad pulse responses. On the other hand the low resistor values will contribute to higher overall power consumption.

TI suggests the following evaluation boards as a guide for high frequency layout and as an aid in device testing and characterization.

| Device    | Package      | Evaluation Board PN |
|-----------|--------------|---------------------|
| LMH6682MA | 8-Pin SOIC   | CLC730036           |
| LMH6682MM | 8-Pin VSSOP  | CLC730123           |
| LMH6683MA | 14-Pin SOIC  | CLC730031           |
| LMH6683MT | 14-Pin TSSOP | CLC730131           |
|           |              |                     |

### **REVISION HISTORY**

| Cł | nanges from Original (April 2013) to Revision A Pa | age |
|----|--|-----|
| •  | Changed layout of National Data Sheet to TI format | 19  |



www.ti.com



#### PACKAGING INFORMATION

| Orderable Device | Status | Package Type | Package<br>Drawing | Pins | Package<br>Qty | Eco Plan<br>(2) | Lead finish/<br>Ball material | MSL Peak Temp      | Op Temp (°C) | Device Marking<br>(4/5) | Samples |
|------------------|--------|--------------|--------------------|------|----------------|-----------------|-------------------------------|--------------------|--------------|-------------------------|---------|
|                  |        |              |                    |      |                |                 | (6)                           |                    |              |                         |         |
| LMH6682MA/NOPB   | ACTIVE | SOIC         | D                  | 8    | 95             | RoHS & Green    | SN                            | Level-1-260C-UNLIM | -40 to 85    | LMH66<br>82MA           | Samples |
| LMH6682MAX/NOPB  | ACTIVE | SOIC         | D                  | 8    | 2500           | RoHS & Green    | SN                            | Level-1-260C-UNLIM | -40 to 85    | LMH66<br>82MA           | Samples |
| LMH6682MM/NOPB   | ACTIVE | VSSOP        | DGK                | 8    | 1000           | RoHS & Green    | SN                            | Level-1-260C-UNLIM | -40 to 85    | A90A                    | Samples |
| LMH6682MMX/NOPB  | ACTIVE | VSSOP        | DGK                | 8    | 3500           | RoHS & Green    | SN                            | Level-1-260C-UNLIM | -40 to 85    | A90A                    | Samples |
| LMH6683MA/NOPB   | ACTIVE | SOIC         | D                  | 14   | 55             | RoHS & Green    | NIPDAU   SN                   | Level-1-260C-UNLIM | -40 to 85    | LMH66<br>83MA           | Samples |
| LMH6683MAX/NOPB  | ACTIVE | SOIC         | D                  | 14   | 2500           | RoHS & Green    | NIPDAU   SN                   | Level-1-260C-UNLIM | -40 to 85    | LMH66<br>83MA           | Samples |
| LMH6683MT/NOPB   | ACTIVE | TSSOP        | PW                 | 14   | 94             | RoHS & Green    | NIPDAU   SN                   | Level-1-260C-UNLIM | -40 to 85    | LMH66<br>83MT           | Samples |
| LMH6683MTX/NOPB  | ACTIVE | TSSOP        | PW                 | 14   | 2500           | RoHS & Green    | NIPDAU   SN                   | Level-1-260C-UNLIM | -40 to 85    | LMH66<br>83MT           | Samples |

<sup>(1)</sup> The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

**PREVIEW**: Device has been announced but is not in production. Samples may or may not be available.

**OBSOLETE:** TI has discontinued the production of the device.

<sup>(2)</sup> RoHS: TI defines "RoHS" to mean semiconductor products that are compliant with the current EU RoHS requirements for all 10 RoHS substances, including the requirement that RoHS substance do not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, "RoHS" products are suitable for use in specified lead-free processes. TI may reference these types of products as "Pb-Free".

RoHS Exempt: TI defines "RoHS Exempt" to mean products that contain lead but are compliant with EU RoHS pursuant to a specific EU RoHS exemption.

Green: TI defines "Green" to mean the content of Chlorine (CI) and Bromine (Br) based flame retardants meet JS709B low halogen requirements of <=1000ppm threshold. Antimony trioxide based flame retardants must also meet the <=1000ppm threshold requirement.

<sup>(3)</sup> MSL, Peak Temp. - The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

<sup>(4)</sup> There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.



#### www.ti.com

### PACKAGE OPTION ADDENDUM

<sup>(5)</sup> Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.

<sup>(6)</sup> Lead finish/Ball material - Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

**Important Information and Disclaimer:** The information provided on this page represents TI's knowledge and belief as of the date that it is provided. TI bases its knowledge and belief on information provided by third parties, and makes no representation or warranty as to the accuracy of such information. Efforts are underway to better integrate information from third parties. TI has taken and continues to take reasonable steps to provide representative and accurate information but may not have conducted destructive testing or chemical analysis on incoming materials and chemicals. TI and TI suppliers consider certain information to be proprietary, and thus CAS numbers and other limited information may not be available for release.

In no event shall TI's liability arising out of such information exceed the total purchase price of the TI part(s) at issue in this document sold by TI to Customer on an annual basis.



Texas

STRUMENTS

#### TAPE AND REEL INFORMATION





#### QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



| *All dimensions are nominal |                 |                    |      |      |                          |                          |            |            |            |            |           |                  |
|-----------------------------|-----------------|--------------------|------|------|--------------------------|--------------------------|------------|------------|------------|------------|-----------|------------------|
| Device                      | Package<br>Type | Package<br>Drawing | Pins | SPQ  | Reel<br>Diameter<br>(mm) | Reel<br>Width<br>W1 (mm) | A0<br>(mm) | B0<br>(mm) | K0<br>(mm) | P1<br>(mm) | W<br>(mm) | Pin1<br>Quadrant |
| LMH6682MAX/NOPB             | SOIC            | D                  | 8    | 2500 | 330.0                    | 12.4                     | 6.5        | 5.4        | 2.0        | 8.0        | 12.0      | Q1               |
| LMH6682MM/NOPB              | VSSOP           | DGK                | 8    | 1000 | 178.0                    | 12.4                     | 5.3        | 3.4        | 1.4        | 8.0        | 12.0      | Q1               |
| LMH6682MMX/NOPB             | VSSOP           | DGK                | 8    | 3500 | 330.0                    | 12.4                     | 5.3        | 3.4        | 1.4        | 8.0        | 12.0      | Q1               |
| LMH6683MAX/NOPB             | SOIC            | D                  | 14   | 2500 | 330.0                    | 16.4                     | 6.5        | 9.35       | 2.3        | 8.0        | 16.0      | Q1               |
| LMH6683MTX/NOPB             | TSSOP           | PW                 | 14   | 2500 | 330.0                    | 12.4                     | 6.95       | 5.6        | 1.6        | 8.0        | 12.0      | Q1               |
| LMH6683MTX/NOPB             | TSSOP           | PW                 | 14   | 2500 | 330.0                    | 12.4                     | 6.95       | 5.6        | 1.6        | 8.0        | 12.0      | Q1               |



www.ti.com

## PACKAGE MATERIALS INFORMATION

25-Sep-2024



| Device          | Package Type | Package Drawing | Pins | SPQ  |
|-----------------|--------------|-----------------|------|------|
| LMH6682MAX/NOPB | SOIC         | D               | 8    | 2500 |
| LMH6682MM/NOPB  | VSSOP        | DGK             | 8    | 1000 |
|                 |              |                 |      |      |

| LMH6682MM/NOPB  | VSSOP | DGK | 8  | 1000 | 208.0 | 191.0 | 35.0 |
|-----------------|-------|-----|----|------|-------|-------|------|
| LMH6682MMX/NOPB | VSSOP | DGK | 8  | 3500 | 367.0 | 367.0 | 35.0 |
| LMH6683MAX/NOPB | SOIC  | D   | 14 | 2500 | 367.0 | 367.0 | 35.0 |
| LMH6683MTX/NOPB | TSSOP | PW  | 14 | 2500 | 367.0 | 367.0 | 35.0 |
| LMH6683MTX/NOPB | TSSOP | PW  | 14 | 2500 | 356.0 | 356.0 | 35.0 |

Length (mm)

367.0

Width (mm)

367.0

Height (mm)

35.0

### TEXAS INSTRUMENTS

www.ti.com

25-Sep-2024

#### TUBE



### - B - Alignment groove width

#### \*All dimensions are nominal

| Device         | Package Name | Package Type | Pins | SPQ | L (mm) | W (mm) | Τ (μm) | B (mm) |
|----------------|--------------|--------------|------|-----|--------|--------|--------|--------|
| LMH6682MA/NOPB | D            | SOIC         | 8    | 95  | 495    | 8      | 4064   | 3.05   |
| LMH6683MA/NOPB | D            | SOIC         | 14   | 55  | 495    | 8      | 4064   | 3.05   |
| LMH6683MT/NOPB | PW           | TSSOP        | 14   | 94  | 530    | 10.2   | 3600   | 3.5    |
| LMH6683MT/NOPB | PW           | TSSOP        | 14   | 94  | 495    | 8      | 2514.6 | 4.06   |

# D0008A



## **PACKAGE OUTLINE**

### SOIC - 1.75 mm max height

SMALL OUTLINE INTEGRATED CIRCUIT



#### NOTES:

1. Linear dimensions are in inches [millimeters]. Dimensions in parenthesis are for reference only. Controlling dimensions are in inches. Dimensioning and tolerancing per ASME Y14.5M.

- 2. This drawing is subject to change without notice.
- 3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed .006 [0.15] per side.
- 4. This dimension does not include interlead flash.
- 5. Reference JEDEC registration MS-012, variation AA.



# D0008A

# **EXAMPLE BOARD LAYOUT**

### SOIC - 1.75 mm max height

SMALL OUTLINE INTEGRATED CIRCUIT



NOTES: (continued)

6. Publication IPC-7351 may have alternate designs.

7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.



### D0008A

# **EXAMPLE STENCIL DESIGN**

### SOIC - 1.75 mm max height

SMALL OUTLINE INTEGRATED CIRCUIT



NOTES: (continued)

8. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.

9. Board assembly site may have different recommendations for stencil design.



# **PW0014A**



## **PACKAGE OUTLINE**

### TSSOP - 1.2 mm max height

SMALL OUTLINE PACKAGE



NOTES:

- 1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M. 2. This drawing is subject to change without notice. 3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not
- exceed 0.15 mm per side.
- 4. This dimension does not include interlead flash. Interlead flash shall not exceed 0.25 mm per side.
- 5. Reference JEDEC registration MO-153.



### PW0014A

# **EXAMPLE BOARD LAYOUT**

### TSSOP - 1.2 mm max height

SMALL OUTLINE PACKAGE



NOTES: (continued)

6. Publication IPC-7351 may have alternate designs.

7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.



### PW0014A

# **EXAMPLE STENCIL DESIGN**

### TSSOP - 1.2 mm max height

SMALL OUTLINE PACKAGE



8. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.

9. Board assembly site may have different recommendations for stencil design.



# **D0014A**



# **PACKAGE OUTLINE**

### SOIC - 1.75 mm max height

SMALL OUTLINE INTEGRATED CIRCUIT



NOTES:

- 1. All linear dimensions are in millimeters. Dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M. 2. This drawing is subject to change without notice. 3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not
- exceed 0.15 mm, per side.
- 4. This dimension does not include interlead flash. Interlead flash shall not exceed 0.43 mm, per side.
- 5. Reference JEDEC registration MS-012, variation AB.



# D0014A

# **EXAMPLE BOARD LAYOUT**

### SOIC - 1.75 mm max height

SMALL OUTLINE INTEGRATED CIRCUIT



NOTES: (continued)

6. Publication IPC-7351 may have alternate designs.

7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.



## D0014A

# **EXAMPLE STENCIL DESIGN**

### SOIC - 1.75 mm max height

SMALL OUTLINE INTEGRATED CIRCUIT



NOTES: (continued)

- 8. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
- 9. Board assembly site may have different recommendations for stencil design.



# **DGK0008A**



# **PACKAGE OUTLINE**

### VSSOP - 1.1 mm max height

SMALL OUTLINE PACKAGE



NOTES:

PowerPAD is a trademark of Texas Instruments.

- 1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M. 2. This drawing is subject to change without notice. 3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not
- exceed 0.15 mm per side.
- 4. This dimension does not include interlead flash. Interlead flash shall not exceed 0.25 mm per side.
- 5. Reference JEDEC registration MO-187.



# DGK0008A

# **EXAMPLE BOARD LAYOUT**

# <sup>™</sup> VSSOP - 1.1 mm max height

SMALL OUTLINE PACKAGE



NOTES: (continued)

- 6. Publication IPC-7351 may have alternate designs.
- 7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.
- 8. Vias are optional depending on application, refer to device data sheet. If any vias are implemented, refer to their locations shown
- on this view. It is recommended that vias under paste be filled, plugged or tented.
- 9. Size of metal pad may vary due to creepage requirement.



# DGK0008A

# **EXAMPLE STENCIL DESIGN**

# <sup>™</sup> VSSOP - 1.1 mm max height

SMALL OUTLINE PACKAGE



11. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.

12. Board assembly site may have different recommendations for stencil design.



#### IMPORTANT NOTICE AND DISCLAIMER

TI PROVIDES TECHNICAL AND RELIABILITY DATA (INCLUDING DATA SHEETS), DESIGN RESOURCES (INCLUDING REFERENCE DESIGNS), APPLICATION OR OTHER DESIGN ADVICE, WEB TOOLS, SAFETY INFORMATION, AND OTHER RESOURCES "AS IS" AND WITH ALL FAULTS, AND DISCLAIMS ALL WARRANTIES, EXPRESS AND IMPLIED, INCLUDING WITHOUT LIMITATION ANY IMPLIED WARRANTIES OF MERCHANTABILITY, FITNESS FOR A PARTICULAR PURPOSE OR NON-INFRINGEMENT OF THIRD PARTY INTELLECTUAL PROPERTY RIGHTS.

These resources are intended for skilled developers designing with TI products. You are solely responsible for (1) selecting the appropriate TI products for your application, (2) designing, validating and testing your application, and (3) ensuring your application meets applicable standards, and any other safety, security, regulatory or other requirements.

These resources are subject to change without notice. TI grants you permission to use these resources only for development of an application that uses the TI products described in the resource. Other reproduction and display of these resources is prohibited. No license is granted to any other TI intellectual property right or to any third party intellectual property right. TI disclaims responsibility for, and you will fully indemnify TI and its representatives against, any claims, damages, costs, losses, and liabilities arising out of your use of these resources.

TI's products are provided subject to TI's Terms of Sale or other applicable terms available either on ti.com or provided in conjunction with such TI products. TI's provision of these resources does not expand or otherwise alter TI's applicable warranties or warranty disclaimers for TI products.

TI objects to and rejects any additional or different terms you may have proposed.

Mailing Address: Texas Instruments, Post Office Box 655303, Dallas, Texas 75265 Copyright © 2024, Texas Instruments Incorporated